

**TO - 92 BIPOLAR TRANSISTORS  
TRANSISTOR(NPN)**

**FEATURES**

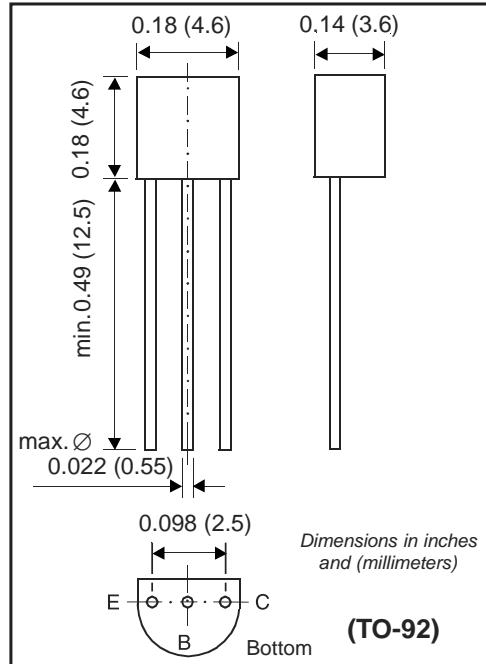
- \* Power dissipation  
PCM: 625mW(Tamb=25°C)
- \* Collector current  
ICM: 0.6 A
- \* Collector-base voltage  
V(BR)CBO: 75 V
- \* Operating and storage junction temperature range  
T<sub>J</sub>,T<sub>STG</sub>: -55°C to+150°C

**MECHANICAL DATA**

- \* Case: Molded plastic
- \* Epoxy: UL 94V-O rate flame retardant
- \* Lead: MIL-STD-202E method 208C guaranteed
- \* Mounting position: Any
- \* Weight: 0.008 gram

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.



**MAXIMUM RATINGS ( @ T<sub>A</sub> = 25°C unless otherwise noted)**

RATINGS	SYMBOL	VALUE	UNITS
Max. Steady State Power Dissipation (1) @TA=25°C Derate above 25°C	P <sub>D</sub>	625	mW
Max. Operating Temperature Range	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

**ELECTRICAL CHARACTERISTICS ( @ T<sub>A</sub> = 25°C unless otherwise noted)**

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	-	-	200	°C/W

Notes : 1. Alumina=0.4\*0.3\*0.024in.99.5% alumina  
2. "Fully ROHS Compliant", "100% Sn plating (Pb-free)".

2011-2

**ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)**

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS**

Collector-Emitter Breakdown Voltage ( $I_C = 10\text{mA}_\text{dc}$ , $I_B = 0$ )	$V_{(\text{BR})\text{CEO}}$	40	-	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10\mu\text{A}_\text{dc}$ , $I_E = 0$ )	$V_{(\text{BR})\text{CBO}}$	75	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10\mu\text{A}_\text{dc}$ , $I_C = 0$ )	$V_{(\text{BR})\text{EBO}}$	6.0	-	Vdc
Collector Cutoff Current ( $V_{CE} = 60\text{Vdc}$ , $V_{EB(\text{off})} = 3.0\text{Vdc}$ )	$I_{CEX}$	-	0.01	$\mu\text{A}_\text{dc}$
Collector Cutoff Current ( $V_{CB} = 60\text{Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 60\text{Vdc}$ , $I_E = 0$ , $TA = 150^\circ\text{C}$ )	$I_{CBO}$	-	0.01	$\mu\text{A}_\text{dc}$
Emitter Cutoff Current ( $V_{EB} = 3.0\text{Vdc}$ , $I_C = 0$ )	$I_{EBO}$	-	0.01	$\mu\text{A}_\text{dc}$
Base Cutoff Current ( $V_{CE} = 60\text{Vdc}$ , $V_{EB(\text{off})} = 3.0\text{Vdc}$ )	$I_{BL}$	-	20	$\text{nA}_\text{dc}$

**ON CHARACTERISTICS**

DC Current Gain ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $TA = -55^\circ\text{C}$ ) ( $I_C = 500\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ ) (1)	$h_{FE}$	35	-	-
-		40	-	-
Collector-Emitter Saturation Voltage (1) ( $I_C = 150\text{mA}_\text{dc}$ , $I_B = 15\text{mA}_\text{dc}$ ) ( $I_C = 500\text{mA}_\text{dc}$ , $I_B = 50\text{mA}_\text{dc}$ )	$V_{CE(\text{sat})}$	-	0.3	Vdc
-		-	1.0	-
Base-Emitter Saturation Voltage (1) ( $I_C = 150\text{mA}_\text{dc}$ , $I_B = 15\text{mA}_\text{dc}$ ) ( $I_C = 500\text{mA}_\text{dc}$ , $I_B = 50\text{mA}_\text{dc}$ )	$V_{BE(\text{sat})}$	0.6	1.2	Vdc
-		-	2.0	-

**SMALL-SIGNAL CHARACTERISTICS**

Current-Gain-Bandwidth Product (2) ( $I_C = 20\text{mA}_\text{dc}$ , $V_{CE} = 20\text{Vdc}$ , $f = 100\text{MHz}$ )	$f_T$	300	-	MHz
Input Capacitance ( $V_{EB} = 0.5\text{Vdc}$ , $I_C = 0$ , $f = 1.0\text{MHz}$ )	$C_{ib0}$	-	25	pF
Input Impedance ( $I_C = 1.0\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ ) ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ )	$h_{ie}$	2.0 0.25	8.0 1.25	kohms
Voltage Feedback Ratio ( $I_C = 1.0\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ ) ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ )	$h_{re}$	-	8.0 4.0	$\times 10^{-4}$
Small-Signal Current Gain ( $I_C = 1.0\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ ) ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ )	$h_{fe}$	50 75	300 375	-
Output Admittance ( $I_C = 1.0\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ ) ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0\text{kHz}$ )	$h_{oe}$	5.0 25	35 200	umhos
Collector Base Time Constant ( $I_E = 20\text{mA}_\text{dc}$ , $V_{CB} = 20\text{Vdc}$ , $f = 31.8\text{MHz}$ )	$r_{b,Cc}$	-	150	ps
Noise Figure ( $I_C = 100\mu\text{A}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $R_S = 1.0\text{kohms}$ , $f = 1.0\text{kHz}$ )	NF	-	4.0	dB

**SWITCHING CHARACTERISTICS**

Delay Time	$t_d$	-	10	-
Rise Time	$t_r$	-	25	ns
Storage Time	$t_s$	-	225	-
Fall Time	$t_f$	-	60	ns

NOTES : 1. Pulse Test: Pulse Width≤300ms, Duty Cycle≤2.0%  
2.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity

**RECTRON**

## RATING AND CHARACTERISTICS CURVES ( PN2222A )

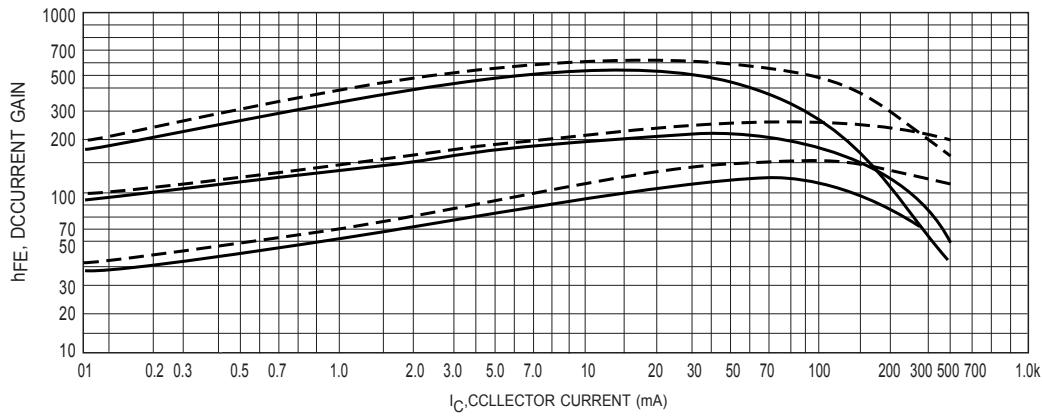


Figure 1. DC Current Gain

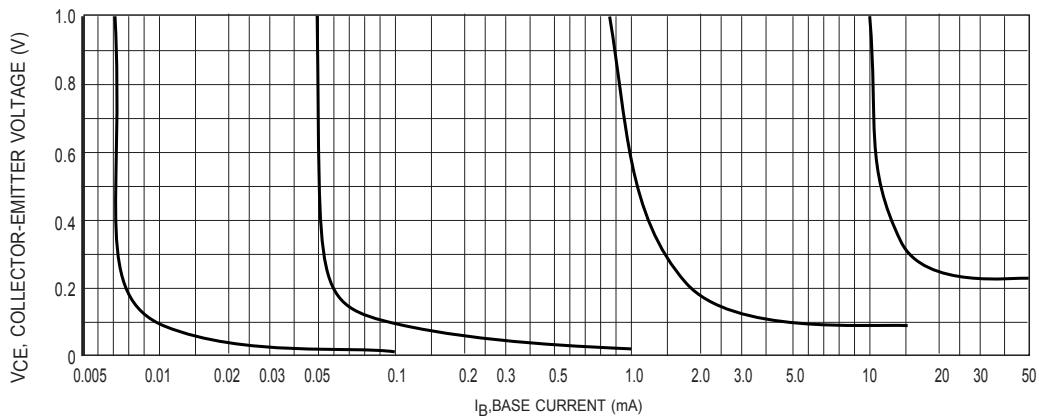


Figure 2. Collector Saturation Region

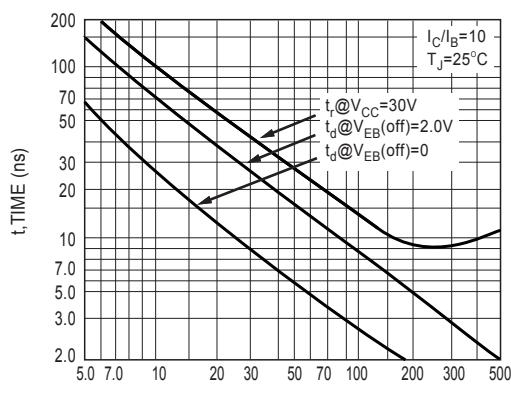


Figure 3.Turn-On Time

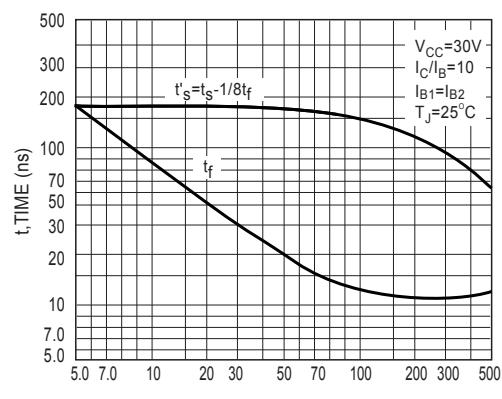


Figure 4.Turn-Off Time

## RATING AND CHARACTERISTICS CURVES ( PN2222A )

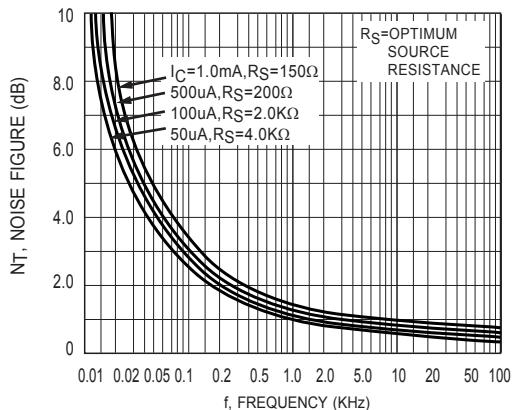


Figure 5.Frequency Effects

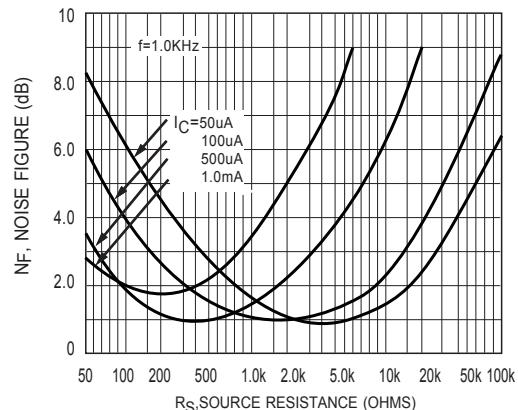


Figure 6.Source Resistance Effects

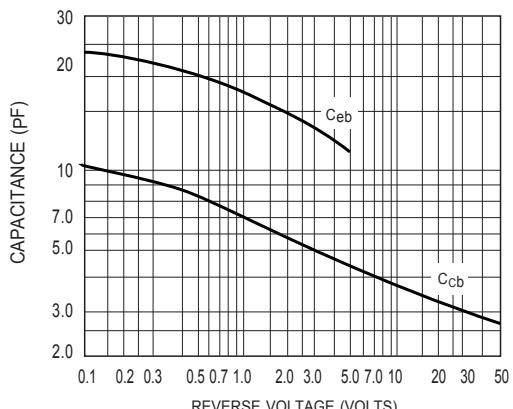


Figure 7.Capacitances

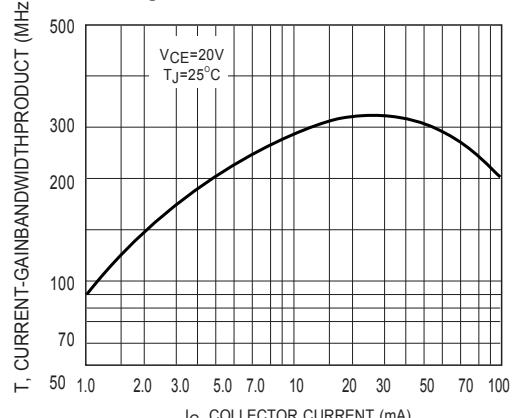


Figure 8.Currunt-Gain Bandwidth Product

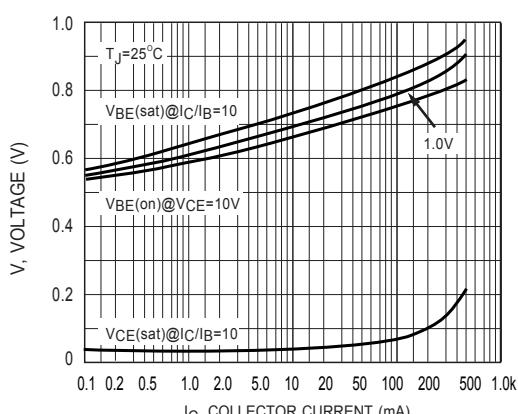


Figure 9."On" Voltages

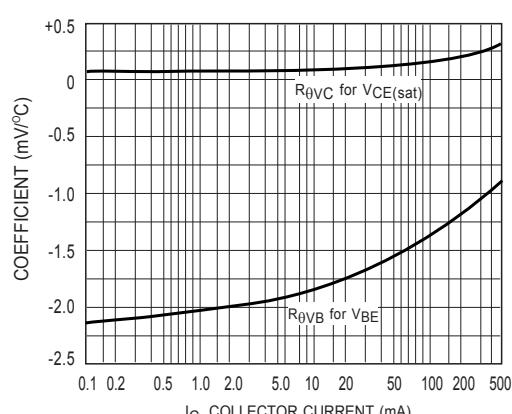


Figure 10.Temperature Coefficients

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- Подбор аналогов;
- Консультации по применению компонента;
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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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